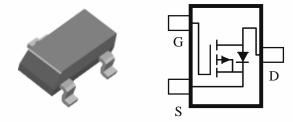
P-Channel 20-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r_{DS(on)} provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe SOT-23 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY

| V _{DS} (V) | r _{DS(on)} (OHM) | I _D (A) |
|---------------------|---------------------------|--------------------|
| -20 | $0.130 @ V_{GS} = -4.5V$ | -2.6 |
| | $0.190 @ V_{GS} = -2.5V$ | -2.1 |



| ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED) | | | | | | |
|--------------------------------------------------------------------------|-----------------------------------------|-----------------|------------|-------|--|--|
| Parameter | | | Maximum | Units | | |
| Drain-Source Voltage | | V _{DS} | -20 | V | | |
| Gate-Source Voltage | | V _{GS} | ′GS ±8 | | | |
| Continuous Dusin Connect ^a | T _A =25°C | I. | -2.6 | | | |
| Continuous Drain Current ^a | $T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$ | ID | -1.5 | А | | |
| Pulsed Drain Current ^b | | I _{DM} | -10 | | | |
| Continuous Source Current (Diode Conduction) ^a | | | ±1.6 | А | | |
| | T _A =25°C | Do | 1.25 | W | | |
| Power Dissipation ^a | $T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$ | гD | 0.8 | ** | | |
| Operating Junction and Storage Temperature Range | | | -55 to 150 | °C | | |

| THERMAL RESISTANCE RATINGS | | | | | |
|------------------------------------------|--------------|--------|---------|-------|--|
| Parameter | | Symbol | Maximum | Units | |
| Maximum Junction-to-Ambient ^a | t <= 5 sec | D | 100 | °C/W | |
| | Steady-State | THJA | 166 | C/VV | |

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

| | Sympol | | Limits | | | TT •4 | |
|-----------------------------------------|---------------------|---------------------------------------------------------------------------|--------|-------|-------|-------|--|
| Parame te r | Symbol | Test Conditions | Min | Тур | Max | Unit | |
| Static | | | | | | | |
| Gate-Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS},I_D=-250\;uA$ | -0.4 | | -1 | | |
| Gate-Body Leakage | Igss | $V_{\rm DS}=0$ V, $V_{\rm GS}=+/\text{-}8$ V | | | ±100 | nA | |
| Zana Cata Valta an Duain Cumant | IDSS | $V_{DS} = -16 V, V_{GS} = 0 V$ | | | -1 | uА | |
| Zero Gate Voltage Drain Current | IDSS | $V_{DS} = -16 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55 ^{\circ}\text{C}$ | | | -10 | uA | |
| On-State Drain Current ^A | Ι | V = -5 V, V = -4.5 V | -3 | | | А | |
| | | $V_{GS} = -4.5 V$, $I_D = -2.6 A$ | | | 0.130 | Ω | |
| Drain-Source On-Resistance ^A | ľDS(on) D(on) | V _{DS} = -2.5 V, L _{DS} = -2.1 A | | | 0.190 | 12 | |
| Forward Tranconductance ^A | g | V = -5 V, I = -2.8 A | | 3 | | S | |
| Diode Forward Voltage | V _{SD} | $I_S = -1.6 \text{ A}, V_{GS} = 0 \text{ V}$ | | -0.70 | | V | |
| Dynamic ^b | fs | DS D | | | | | |
| Total Gate Charge | Qg | | | 12.2 | | nC | |
| Gate-Source Charge | Qgs | $V_{DS} = -5 V, V_{GS} = -4.5 V,$ ID = -2.6 A | | 1.1 | | | |
| Gate-Drain Charge | Qgd | ID = -2.0 A | | 1.5 | | | |
| Turn-On Delay Time | t _{d(on)} | | | 6.5 | | | |
| Rise Time | tr | $V_{DD} = -5 \text{ V}, R_L = 5 \text{ OHM},$ | | 20 | | ns | |
| Turn-Off Delay Time | t _{d(off)} | $V_{\rm GEN}=-4.5~V,R_{\rm G}=6~OHM$ | | 31 | | | |
| Fall-Time | tf | | | 21 | | 1 | |

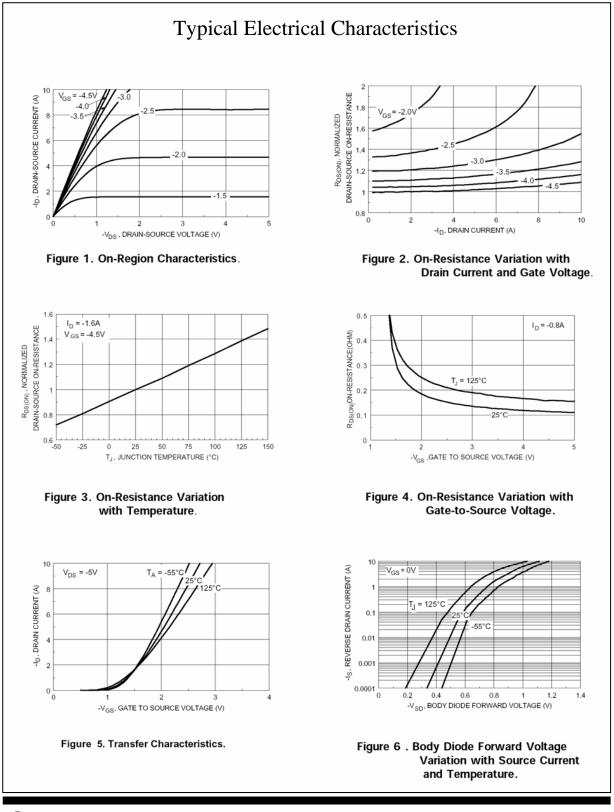
Notes

- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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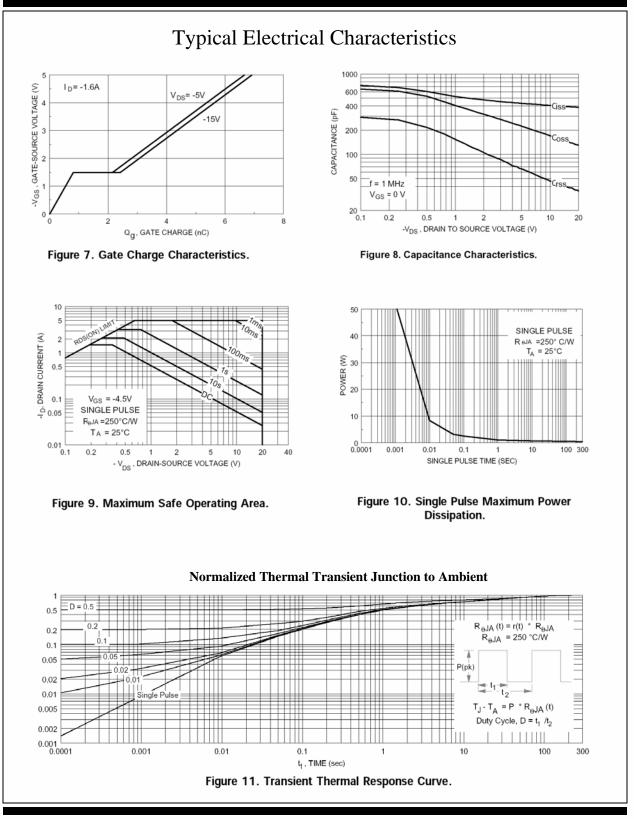
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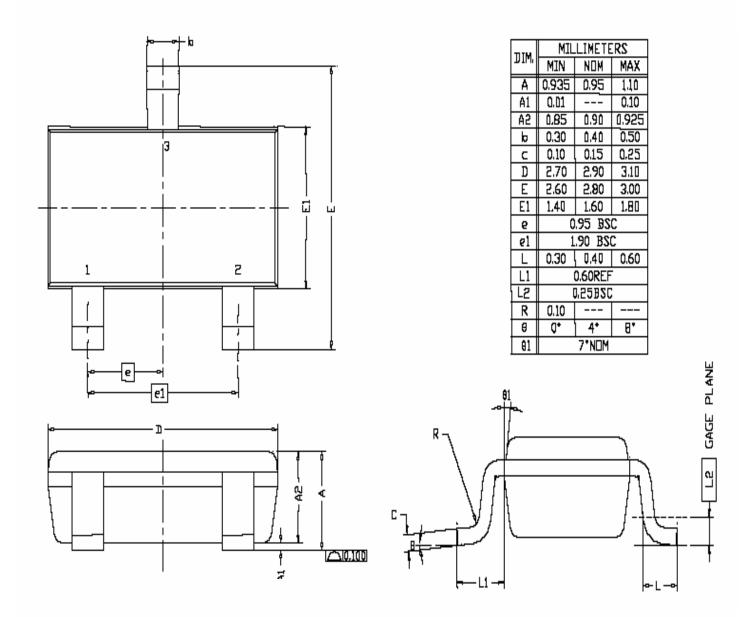
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AO3403/MC3403



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Package Information



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Ordering information

• AM2301P-T1-XX

- A: Analog Power
- M: MOSFET
- 2301: Part number
- P: P-Channel
- T1: Tape & reel
- XX: Blank: StandardPF: Leadfree